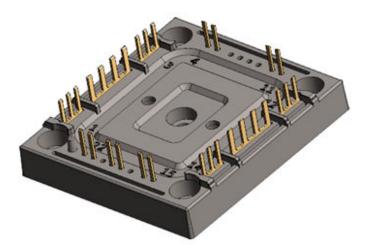
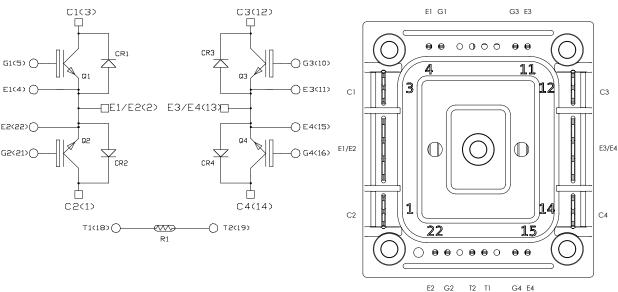
# Double Dual Common Emitter High-Speed IGBT4 Power Module

#### **Product Overview**

The MSCGLQ75DDU120CTBL3NG device is a 1200 V/75 A double dual common emitter high-speed IGBT4 power module.





All ratings at T<sub>J</sub> = 25 °C, unless otherwise specified.

Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

#### **Features**

The following are the key features of MSCGLQ75DDU120CTBL3NG device:

- · High speed IGBT4
  - Low voltage drop
  - Low leakage current
  - Low switching losses
- · SiC Schottky Diode
  - Zero reverse recovery
  - Zero forward recovery
  - Temperature independent switching behavior
  - Positive temperature coefficient on V<sub>F</sub>
- · Ultra-low weight and profile
- Kelvin emitter for easy drive
- Si<sub>3</sub>N<sub>4</sub> substrate with thick copper for improved thermal performance
- Internal thermistor for temperature monitoring
- Extended temperature range

#### **Benefits**

The following are the benefits of MSCGLQ75DDU120CTBL3NG device:

- High efficiency converter
- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction-to-heatsink thermal resistance
- Low profile
- RoHS compliant
- Solderable terminals both for power and signal for easy PCB mounting
- Very integrated power conversion system

## **Application**

The following are the applications of MSCGLQ75DDU120CTBL3NG device:

- · High reliability power systems
- AC switches

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## 1. Electrical Specifications

This section provides the electrical specifications of MSCGLQ75DDU120CTBL3NG device.

#### 1.1 IGBT4 Characteristics (Per IGBT)

The following table lists the absolute maximum ratings of MSCGLQ75DDU120CTBL3NG device.

**Table 1-1. Absolute Maximum Ratings** 

Symbol	Parameter	Parameter I		Unit
V <sub>CES</sub>	Collector-Emitter voltage	or-Emitter voltage		V
I <sub>C</sub>	C Continuous collector current T <sub>H</sub> = 2		160	Α
		T <sub>H</sub> = 80 °C	75	
I <sub>CM</sub>	Pulsed collector current	T <sub>H</sub> = 25 °C	250	
V <sub>GE</sub>	Gate-Emitter voltage	Sate-Emitter voltage		V
P <sub>D</sub>	Power dissipation		470	W

The following table lists the electrical characteristics of MSCGLQ75DDU120CTBL3NG device.

**Table 1-2. Electrical Characteristics** 

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I <sub>CES</sub>	Zero gate voltage collector current	V <sub>GE</sub> = 0 V V <sub>CE</sub> = 1200 V		_	_	50	μΑ
V <sub>CE(sat)</sub>	Collector emitter	V <sub>GE</sub> = 15 V	T <sub>J</sub> = 25 °C	1.7	2.05	2.4	V
	saturation voltage	I <sub>C</sub> = 75 A	T <sub>J</sub> = 150 °C	_	2.6	_	
$V_{GE(th)}$	Gate threshold voltage	$V_{GE} = V_{CE}$ $I_C = 2.6 \text{ mA}$		5.3	5.8	6.3	V
I <sub>GES</sub>	Gate-Emitter leakage current	V <sub>GE</sub> = 20 V V <sub>CE</sub> = 0 V		_	_	150	nA

**Electrical Specifications** 

The following table lists the dynamic characteristics of MSCGLQ75DDU120CTBL3NG device.

#### **Table 1-3. Dynamic Characteristics**

Symbol	Characteristic	Test Condition	าร		Min	Тур	Max	Unit
C <sub>ies</sub>	Input capacitance	V <sub>GE</sub> = 0 V	V <sub>GE</sub> = 0 V			4400	_	pF
C <sub>oes</sub>	Output capacitance	V <sub>CE</sub> = 25 V			_	250	_	
C <sub>res</sub>	Reverse transfer capacitance	f = 1 MHz			_	235	_	
Q <sub>g</sub>	Gate charge	$V_{GE} = 15 \text{ V}$ $V_{CE} = 960 \text{ V}$ $I_{C} = 75 \text{ A}$	V <sub>CE</sub> = 960 V		_	325	_	nC
T <sub>d(on)</sub>	Turn-on delay time	V <sub>GE</sub> = ±15 V		T <sub>J</sub> = 150 °C	_	30	_	ns
T <sub>r</sub>	Rise time	V <sub>Bus</sub> = 600 V	' <sub>Bus</sub> = 600 V	_	49	_		
T <sub>d(off)</sub>	Turn-off delay time	I <sub>C</sub> = 75 A			_	366	_	
T <sub>f</sub>	Fall time	$R_G = 6.4 \Omega$				48	_	
E <sub>on</sub>	Turn-on switching energy	V <sub>GE</sub> = ±15 V V <sub>Bus</sub> = 600 V		T <sub>J</sub> = 150 °C	_	3.84	_	mJ
E <sub>off</sub>	Turn-off switching energy	$I_{C} = 75 \text{ A}$ $R_{G} = 6.4 \Omega$		T <sub>J</sub> = 150 °C	_	3.84	_	
R <sub>G</sub>	Integrated gate resist	or			_	10	_	Ω
I <sub>SC</sub>	Short circuit data	$V_{GE} \le 15 \text{ V}$ $V_{Bus} = 900 \text{ V}$ $t_p \le 10  \mu \text{s}$		T <sub>j</sub> = 150 °C	_	260		A
R <sub>thJH</sub>	Junction-to-heatsink resistance	thermal	$\lambda_{\text{paste}} = 3.4 \text{ W}$	/mK		0.318		°C/W

#### 1.2 SiC Diode Ratings and Characteristics (Per SiC Diode)

The following table lists the SiC diode ratings and characteristics of MSCGLQ75DDU120CTBL3NG device.

Table 1-4. SiC Diode Ratings and Characteristics

Symbol	Characteristic	Test Condition	ons		Min	Тур	Max	Unit
$V_{RRM}$	Peak repetitive reverse	voltage			<u> </u>	_	1200	V
I <sub>RM</sub>	Reverse leakage	age V <sub>R</sub> = 1200 V	T <sub>J</sub> = 25 °C	_	10	200	μA	
	current				_	250	_	
I <sub>F</sub>	DC forward current			T <sub>H</sub> = 100 °C	_	50	_	А
V <sub>F</sub>	Diode forward voltage   I <sub>F</sub> = 50 A			T <sub>J</sub> = 25 °C	_	1.5	1.8	V
		1		T <sub>J</sub> = 175 °C	_	2.1	_	
Q <sub>C</sub>	Total capacitive charge	V <sub>R</sub> = 600 V			_	224	_	nC
С	Total capacitance	f = 1 MHz V <sub>R</sub> = 400 V		_	246	_	pF	
		f = 1 MHz V <sub>R</sub> = 800 V		_	182	_		
R <sub>thJH</sub>	Junction-to-heatsink the resistance	rmal	$\lambda_{\text{paste}} = 3.4 \ \text{V}$	N/mK	_	0.635	_	°C/W

#### 1.3 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the MSCGLQ75DDU120CTBL3NG device.

Table 1-5. Thermal and Package Characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
V <sub>ISOL</sub>	RMS isolation voltage, any terminal to case t = 1 min, 50 Hz/60 Hz			2500	_	_	V
T <sub>J</sub>	Operating junction temperature range			<b>-</b> 55	_	175	°C
T <sub>JOP</sub>	Recommended junction temperature under switching conditions			<b>-</b> 55	_	T <sub>Jmax</sub> –25	
T <sub>STG</sub>	Storage case temperature			<b>–</b> 55	_	125	
T <sub>C</sub>	Operating case temperature			<b>-</b> 55	_	125	
Torque	Mounting torque	que To heatsink M3			_	0.9	N.m
Wt	Package weight			_	32.5	_	g

The following table lists the temperature sensor NTC of the MSCGLQ75DDU120CTBL3NG device.

Table 1-6. Temperature Sensor NTC

Symbol	Characteristic		Min	Тур	Max	Unit
R <sub>25</sub>	Resistance at 25 °C		_	50	_	kΩ
$\Delta R_{25}/R_{25}$	25		_	5	_	%
B <sub>25/85</sub>	T <sub>25</sub> = 298.15 K		_	3952	_	K
ΔΒ/Β	_	T <sub>C</sub> = 100 °C	_	4	_	%

$$R_{T} = \frac{R_{25}}{\exp \left[ B_{25/85} \left( \frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_{T}: \text{ Thermistor value at T}$$

Note: See APT0406—Using NTC Temperature Sensor Integrated into Power Module for more information.

### 1.4 Typical IGBT4 Performance Curve (Per IGBT)

This section shows the typical IGBT4 performance curves of MSCGLQ75DDU120CTBL3NG device.

Figure 1-1. Junction-to-Heatsink Thermal Impedance

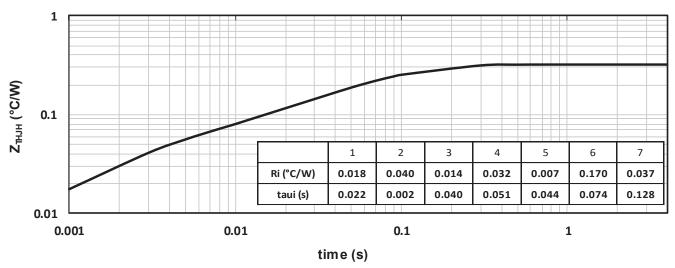


Figure 1-2. Output Characteristics ( $V_{GE} = 15 \text{ V}$ )

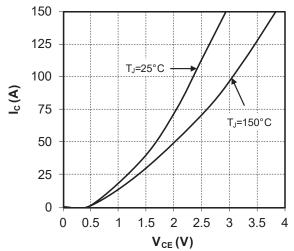


Figure 1-3. Output Characteristics

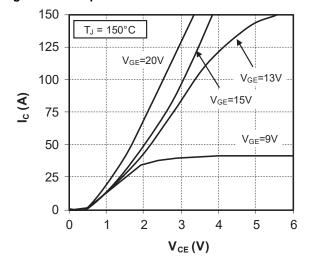


Figure 1-4. Transfer Characteristics

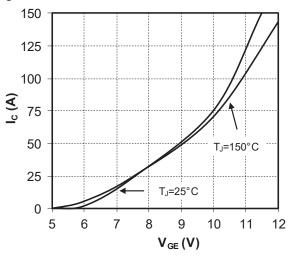


Figure 1-5. Energy Losses vs. Collector Current

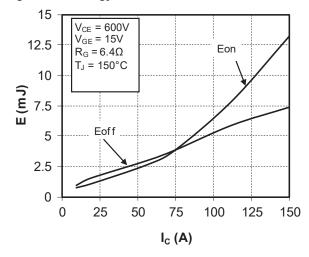


Figure 1-6. Switching Energy Losses vs. Gate Resistance

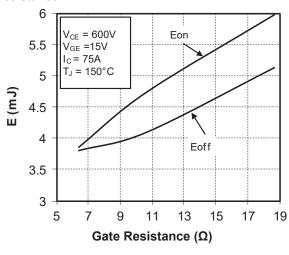
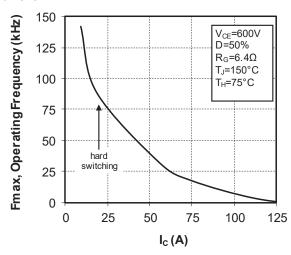


Figure 1-7. Operating Frequency vs. Collector Current



#### 1.5 Typical SiC Diode Performance Curves (Per SiC Diode)

This section shows the typical SiC diode performance curves of MSCGLQ75DDU120CTBL3NG device.

Figure 1-8. Junction-to-Heatsink Thermal Impedance

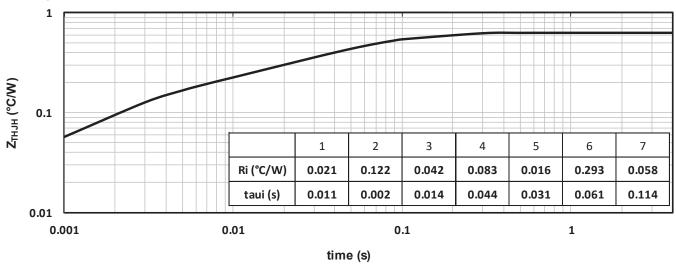


Figure 1-9. Forward Characteristics

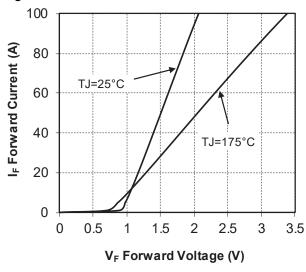
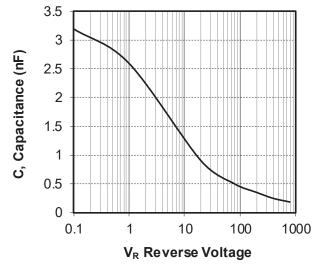


Figure 1-10. Capacitance vs. Reverse Voltage



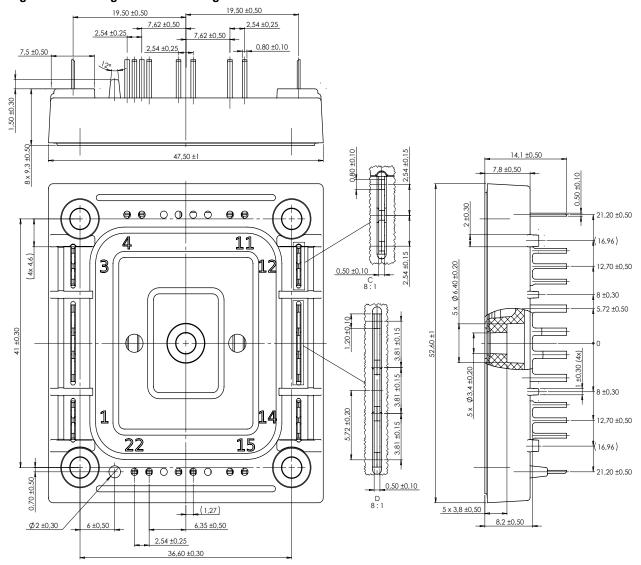
## 2. Package Specifications

The following section shows the package specification of MSCGLQ75DDU120CTBL3NG device.

#### 2.1 Package Outline

The following figure shows the package outline drawing of MSCGLQ75DDU120CTBL3NG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



**Revision History** 

# 3. Revision History

Revision	Date	Description
Α	07/2021	Initial revision

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